

LM431

Adjustable Precision Zener Shunt Regulator

General Description

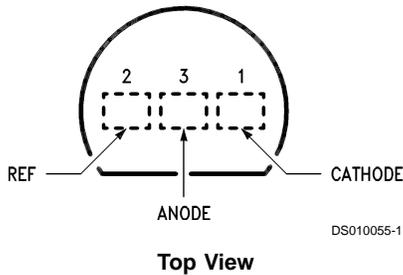
The LM431 is a 3-terminal adjustable shunt regulator with guaranteed temperature stability over the entire temperature range of operation. It is now available in a chip sized package (4-Bump micro SMD) using National's micro SMD package technology. The output voltage may be set at any level greater than 2.5V (V_{REF}) up to 36V merely by selecting two external resistors that act as a voltage divided network. Due to the sharp turn-on characteristics this device is an excellent replacement for many zener diode applications.

Features

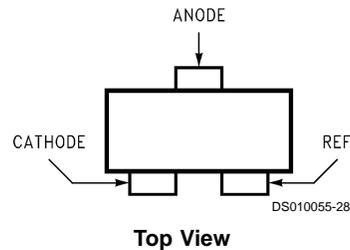
- Average temperature coefficient 50 ppm/°C
- Temperature compensated for operation over the full temperature range
- Programmable output voltage
- Fast turn-on response
- Low output noise
- LM431 in micro SMD package
- See AN-1112 for micro SMD considerations

Connection Diagrams

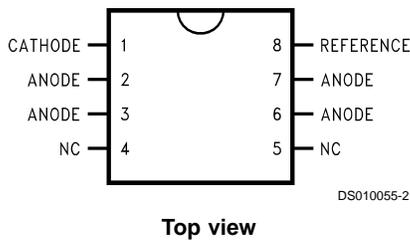
TO-92: Plastic Package



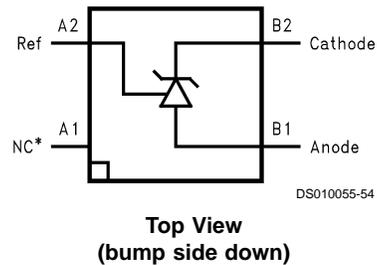
SOT-23: 3-Lead Small Outline



SO-8: 8-Pin Surface Mount



4-Bump micro SMD



Note: *NC = Not internally connected. Must be electrically isolated from the rest of the circuit for the microSMD package.

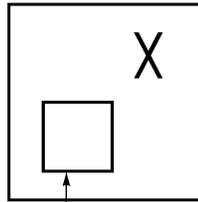
Ordering Information

| Package | Typical Accuracy Order Number/Package Marking | | | Temperature Range | Transport Media | NSC Drawing |
|-----------|---|-----------------------|---------------------------------|-------------------|---|-------------|
| | 0.5% | 1% | 2% | | | |
| TO-92 | LM431CCZ/ LM431CCZ | LM431BCZ/ LM431BCZ | LM431ACZ/ LM431ACZ | 0°C to +70°C | Rails | Z03A |
| | LM431CIZ/ LM431CIZ | LM431BIZ/ LM431BIZ | LM431AIZ/ LM431AIZ | -40°C to +85°C | | |
| SO-8 | LM431CCM/ 431CCM | LM431BCM/ 431BCM | LM431ACM/ LM431ACM | 0°C to +70°C | Rails and Tape & Reel | M08A |
| | LM431CIM/ 431CIM | LM431BIM/ 431BIM | LM431AIM/ LM431AIM | -40°C to +85°C | | |
| SOT-23 | LM431CCM3/ N1B | LM431BCM3/ N1D | LM431ACM3/ N1F | 0°C to +70°C | Rails and Tape & Reel | MF03A |
| | LM431CIM3 N1A | LM431BIM3 N1C | LM431AIM3 N1E | -40°C to +85°C | | |
| micro SMD | - | - | LM431AIBP LM431AIBPX(Note 1) | -40°C to +85°C | 250 Units Tape and Reel 3k Units Tape and Reel | BPA04AFB |

Note 1: The micro SMD package marking is a 1 digit manufacturing Date Code only

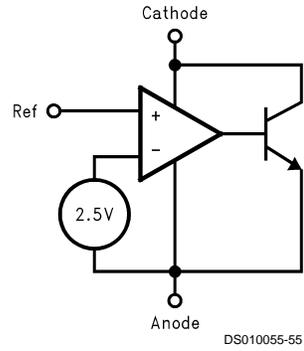
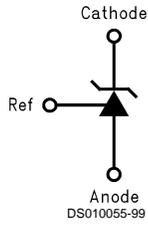
micro SMD Top View Marking Example

X = Date Code



Pin A1 Identifier
DS010055-56

Symbol and Functional Diagrams



DC Test Circuits

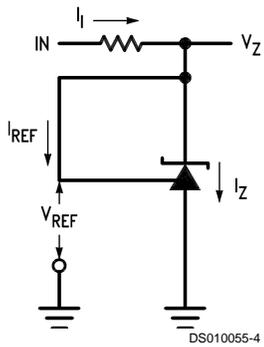
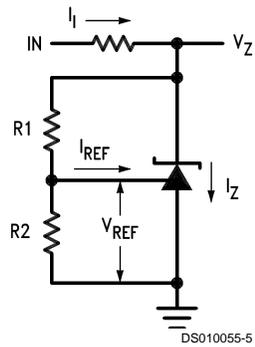


FIGURE 1. Test Circuit for $V_Z = V_{REF}$



Note: $V_Z = V_{REF} (1 + R1/R2) + I_{REF} \cdot R1$

FIGURE 2. Test Circuit for $V_Z > V_{REF}$

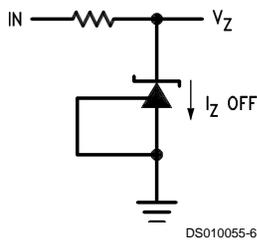


FIGURE 3. Test Circuit for Off-State Current

Absolute Maximum Ratings (Note 2)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

| | |
|----------------------------------|--------------------|
| Storage Temperature Range | -65°C to +150°C |
| Operating Temperature Range | |
| Industrial (LM431xI) | -40°C to +85°C |
| Commercial (LM431xC) | 0°C to +70°C |
| Soldering Information | |
| Infrared or Convection (20 sec.) | 235°C |
| Wave Soldering (10 sec.) | 260°C (lead temp.) |
| Cathode Voltage | 37V |
| Continuous Cathode Current | -10 mA to +150 mA |

| | |
|---|-------|
| Reference Voltage | -0.5V |
| Reference Input Current | 10 mA |
| Internal Power Dissipation (Notes 3, 4) | |
| TO-92 Package | 0.78W |
| SO-8 Package | 0.81W |
| SOT-23 Package | 0.28W |
| micro SMD Package | 0.30W |

Operating Conditions

| | Min | Max |
|-----------------|-----------|--------|
| Cathode Voltage | V_{REF} | 37V |
| Cathode Current | 1.0 mA | 100 mA |

LM431
Electrical Characteristics

$T_A = 25^\circ\text{C}$ unless otherwise specified

| Symbol | Parameter | Conditions | Min | Typ | Max | Units |
|-------------------------------------|---|--|-------|-------|-------|---------------|
| V_{REF} | Reference Voltage | $V_Z = V_{REF}$, $I_I = 10\text{ mA}$ LM431A (Figure 1) | 2.440 | 2.495 | 2.550 | V |
| | | $V_Z = V_{REF}$, $I_I = 10\text{ mA}$ LM431B (Figure 1) | 2.470 | 2.495 | 2.520 | V |
| | | $V_Z = V_{REF}$, $I_I = 10\text{ mA}$ LM431C (Figure 1) | 2.485 | 2.500 | 2.510 | V |
| V_{DEV} | Deviation of Reference Input Voltage Over Temperature (Note 5) | $V_Z = V_{REF}$, $I_I = 10\text{ mA}$, $T_A = \text{Full Range}$ (Figure 1) | | 8.0 | 17 | mV |
| $\frac{\Delta V_{REF}}{\Delta V_Z}$ | Ratio of the Change in Reference Voltage to the Change in Cathode Voltage | $I_Z = 10\text{ mA}$ (Figure 2) | | -1.4 | -2.7 | mV/V |
| | | V_Z from V_{REF} to 10V V_Z from 10V to 36V | | -1.0 | -2.0 | |
| I_{REF} | Reference Input Current | $R_1 = 10\text{ k}\Omega$, $R_2 = \infty$, $I_I = 10\text{ mA}$ (Figure 2) | | 2.0 | 4.0 | μA |
| αI_{REF} | Deviation of Reference Input Current over Temperature | $R_1 = 10\text{ k}\Omega$, $R_2 = \infty$, $I_I = 10\text{ mA}$, $T_A = \text{Full Range}$ (Figure 2) | | 0.4 | 1.2 | μA |
| $I_{Z(MIN)}$ | Minimum Cathode Current for Regulation | $V_Z = V_{REF}$ (Figure 1) | | 0.4 | 1.0 | mA |
| $I_{Z(OFF)}$ | Off-State Current | $V_Z = 36\text{V}$, $V_{REF} = 0\text{V}$ (Figure 3) | | 0.3 | 1.0 | μA |
| r_Z | Dynamic Output Impedance (Note 6) | $V_Z = V_{REF}$, LM431A, Frequency = 0 Hz (Figure 1) | | | 0.75 | Ω |
| | | $V_Z = V_{REF}$, LM431B, LM431C Frequency = 0 Hz (Figure 1) | | | 0.50 | Ω |

Note 2: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Electrical specifications do not apply when operating the device beyond its rated operating conditions.

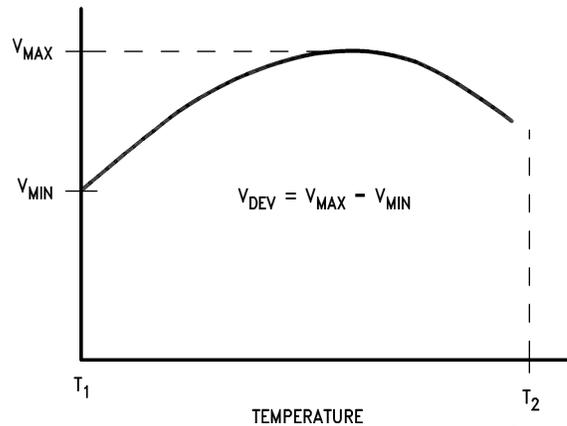
Note 3: $T_{J\text{ Max}} = 150^\circ\text{C}$.

Note 4: Ratings apply to ambient temperature at 25°C. Above this temperature, derate the TO-92 at 6.2 mW/°C, the SO-8 at 6.5 mW/°C, the SOT-23 at 2.2 mW/°C and the micro SMD at 3mW/°C.

Note 5: Deviation of reference input voltage, V_{DEV} , is defined as the maximum variation of the reference input voltage over the full temperature range.

LM431

Electrical Characteristics (Continued)



The average temperature coefficient of the reference input voltage, αV_{REF} , is defined as:

$$\alpha V_{REF} \frac{\text{ppm}}{^{\circ}\text{C}} = \frac{\pm \left[\frac{V_{\text{Max}} - V_{\text{Min}}}{V_{\text{REF}}(\text{at } 25^{\circ}\text{C})} \right] 10^6}{T_2 - T_1} = \frac{\pm \left[\frac{V_{\text{DEV}}}{V_{\text{REF}}(\text{at } 25^{\circ}\text{C})} \right] 10^6}{T_2 - T_1}$$

Where:

$T_2 - T_1$ = full temperature change (0-70°C).

αV_{REF} can be positive or negative depending on whether the slope is positive or negative.

Example: $V_{DEV} = 8.0 \text{ mV}$, $V_{REF} = 2495 \text{ mV}$, $T_2 - T_1 = 70^{\circ}\text{C}$, slope is positive.

$$\alpha V_{REF} = \frac{\left[\frac{8.0 \text{ mV}}{2495 \text{ mV}} \right] 10^6}{70^{\circ}\text{C}} = +46 \text{ ppm}/^{\circ}\text{C}$$

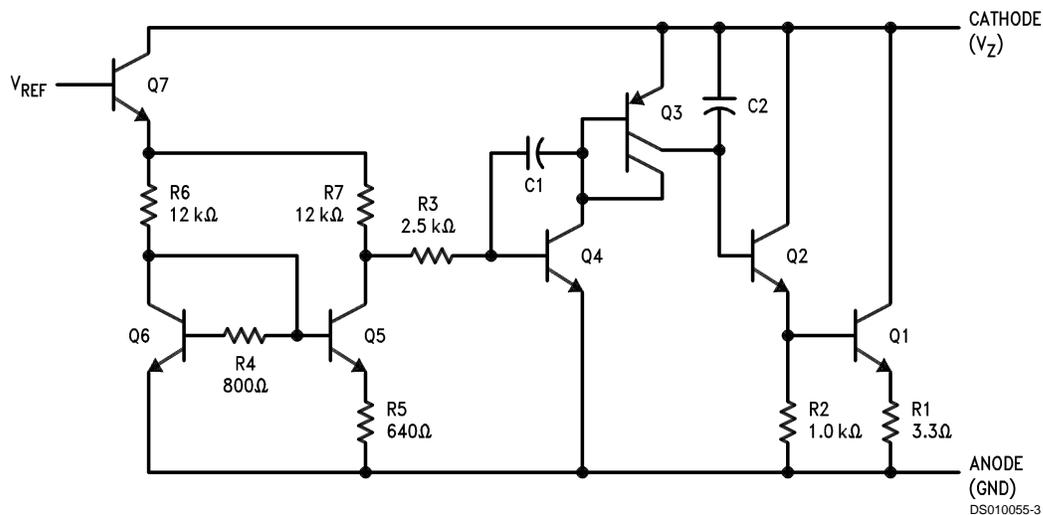
Note 6: The dynamic output impedance, r_z , is defined as:

$$r_z = \frac{\Delta V_z}{\Delta I_z}$$

When the device is programmed with two external resistors, R1 and R2, (see Figure 2), the dynamic output impedance of the overall circuit, r_z , is defined as:

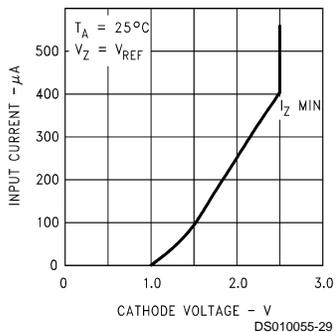
$$r_z = \frac{\Delta V_z}{\Delta I_z} \approx \left[r_z \left(1 + \frac{R1}{R2} \right) \right]$$

Equivalent Circuit

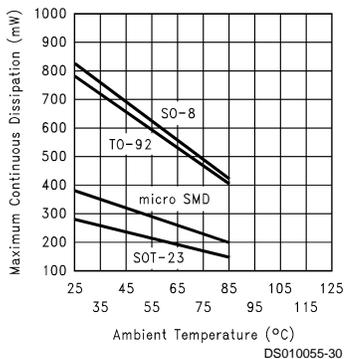


Typical Performance Characteristics

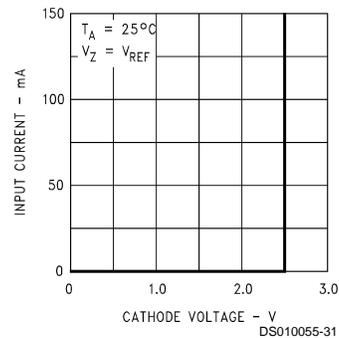
Input Current vs V_Z



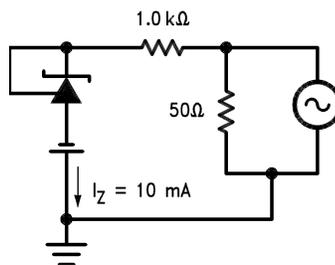
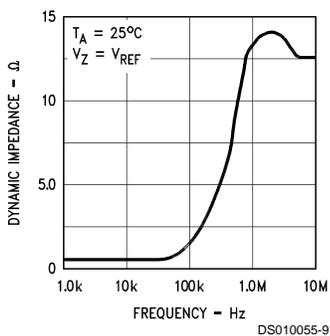
Thermal Information



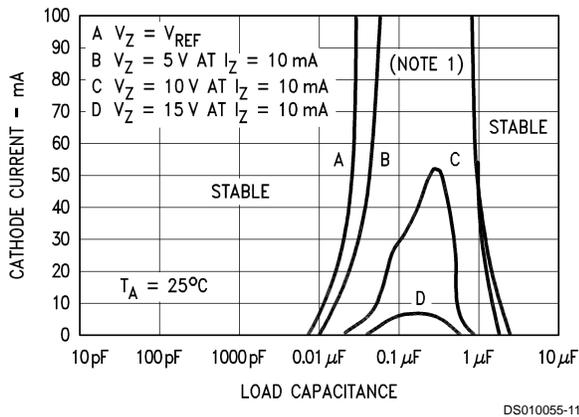
Input Current vs V_Z



Dynamic Impedance vs Frequency

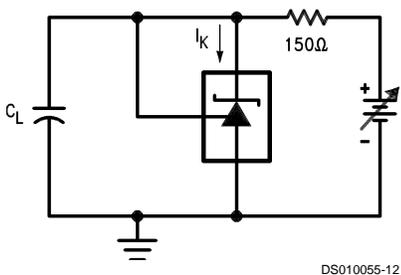


Stability Boundary Conditions

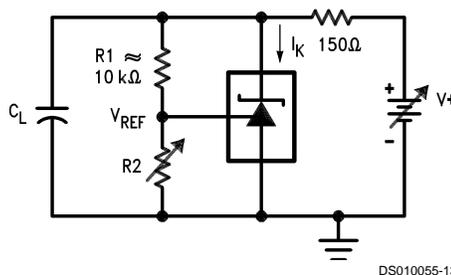


Note: The areas under the curves represent conditions that may cause the device to oscillate. For curves B, C, and D, R_2 and V^+ were adjusted to establish the initial V_Z and I_Z conditions with $C_L = 0$. V^+ and C_L were then adjusted to determine the ranges of stability.

Test Circuit for Curve A Above

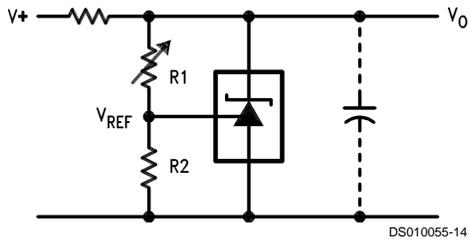


Test Circuit for Curves B, C and D Above



Typical Applications

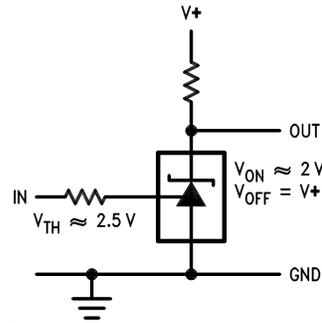
Shunt Regulator



DS010055-14

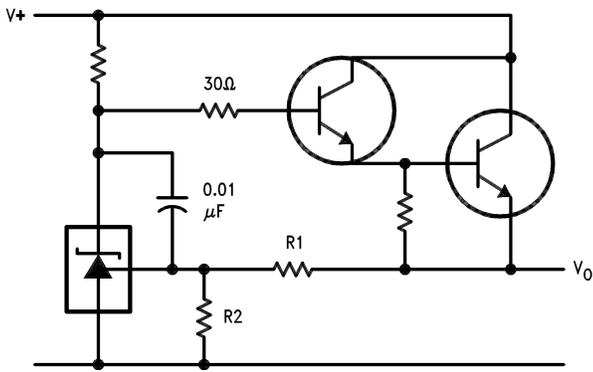
$$V_O \approx \left(1 + \frac{R_1}{R_2}\right) V_{REF}$$

Single Supply Comparator with Temperature Compensated Threshold



DS010055-15

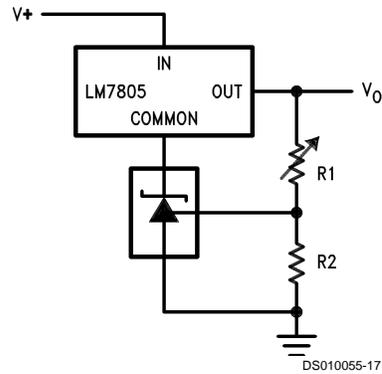
Series Regulator



DS010055-16

$$V_O \approx \left(1 + \frac{R_1}{R_2}\right) V_{REF}$$

Output Control of a Three Terminal Fixed Regulator

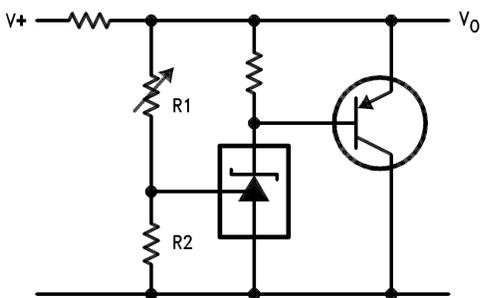


DS010055-17

$$V_O = \left(1 + \frac{R_1}{R_2}\right) V_{REF}$$

$$V_{O\ MIN} = V_{REF} + 5V$$

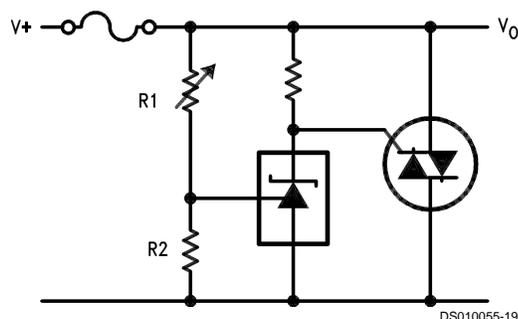
Higher Current Shunt Regulator



DS010055-18

$$V_O \approx \left(1 + \frac{R_1}{R_2}\right) V_{REF}$$

Crow Bar

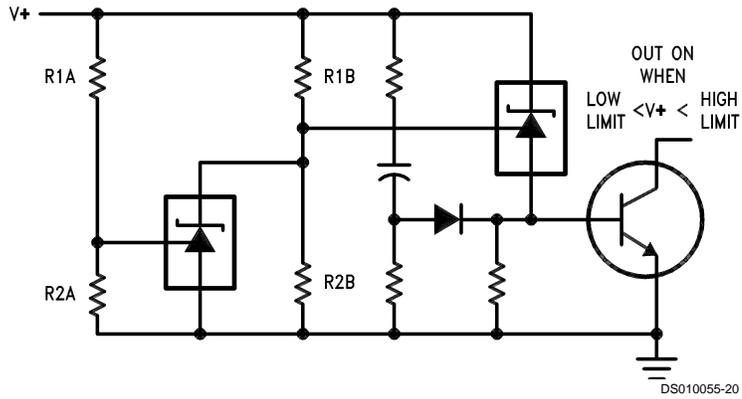


DS010055-19

$$V_{LIMIT} \approx \left(1 + \frac{R_1}{R_2}\right) V_{REF}$$

Typical Applications (Continued)

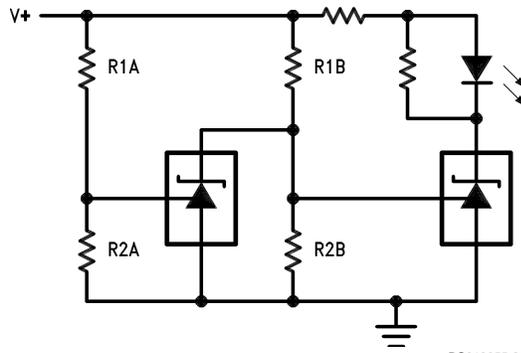
Over Voltage/Under Voltage Protection Circuit



$$\text{LOW LIMIT} \approx V_{\text{REF}} \left(1 + \frac{R1B}{R2B} \right) + V_{\text{BE}}$$

$$\text{HIGH LIMIT} \approx V_{\text{REF}} \left(1 + \frac{R1A}{R2A} \right)$$

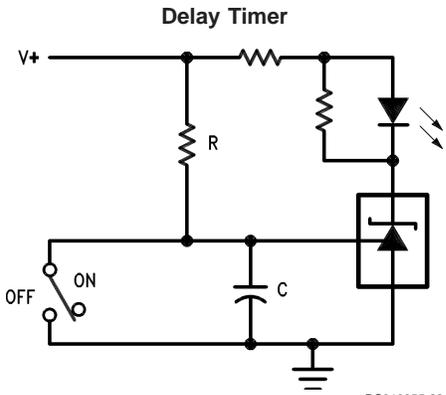
Voltage Monitor



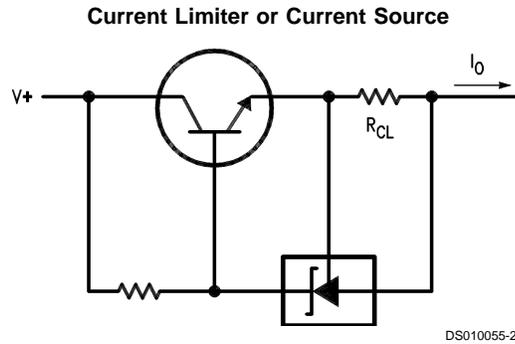
$$\text{LOW LIMIT} \approx V_{\text{REF}} \left(1 + \frac{R1B}{R2B} \right) \quad \text{LED ON WHEN LOW LIMIT} < V^+ < \text{HIGH LIMIT}$$

$$\text{HIGH LIMIT} \approx V_{\text{REF}} \left(1 + \frac{R1A}{R2A} \right)$$

Typical Applications (Continued)

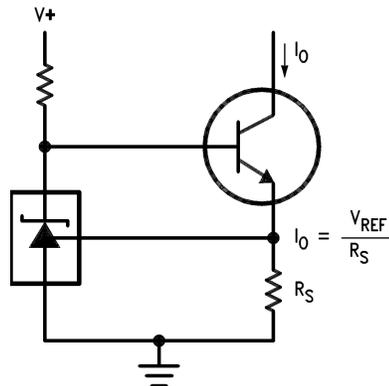


$$\text{DELAY} = R \cdot C \cdot \ln \frac{V^+}{(V^+) - V_{\text{REF}}}$$



$$I_o = \frac{V_{\text{REF}}}{R_{\text{CL}}}$$

Constant Current Sink



$$I_o = \frac{V_{\text{REF}}}{R_S}$$

Application Info

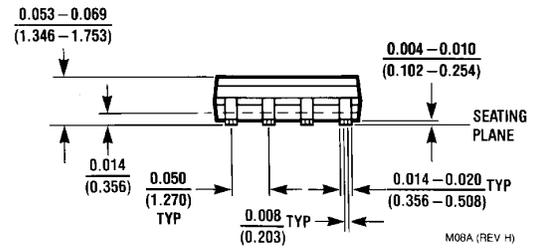
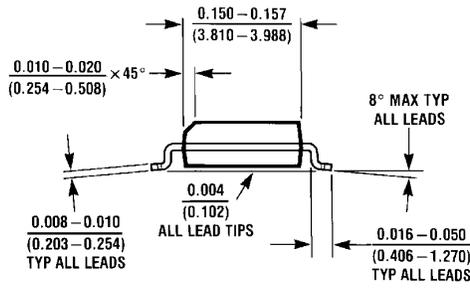
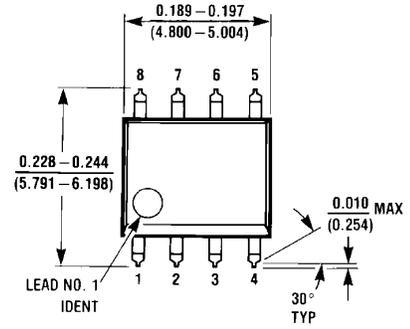
1.0 Mounting

To ensure that the geometry of the micro SMD package maintains good physical contact with the printed circuit board, pin A1 (NC) must be soldered to the pcb. Please see AN-1112 for more detailed information regarding board mounting techniques for the micro SMD package.

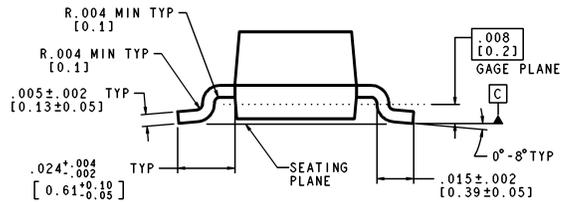
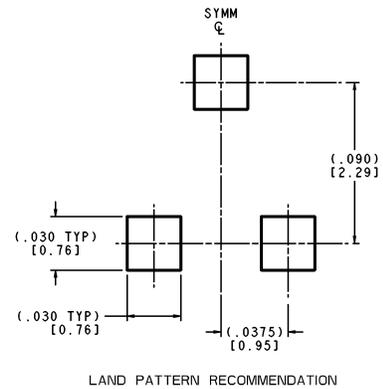
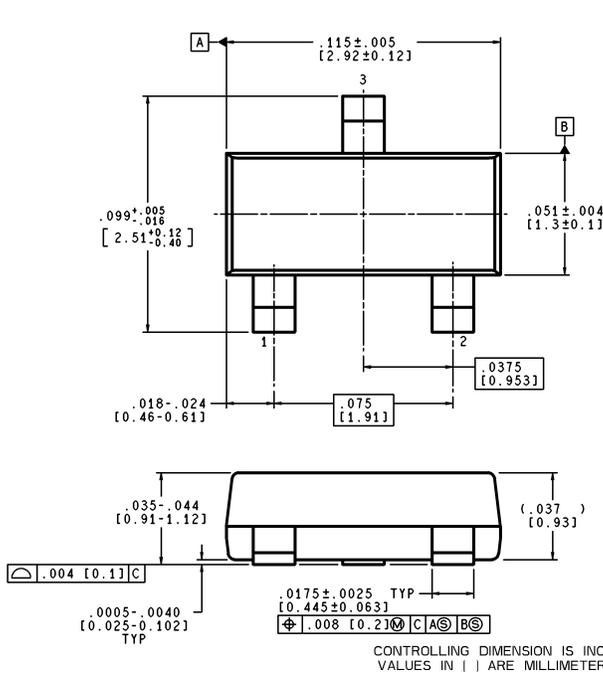
2.0 LM431 micro SMD Light Sensitivity

When the LM431 micro SMD package is exposed to bright sunlight, normal office fluorescent light, and other LED's and lasers, it operates within the guaranteed limits specified in the electrical characteristics table.

Physical Dimensions inches (millimeters) unless otherwise noted



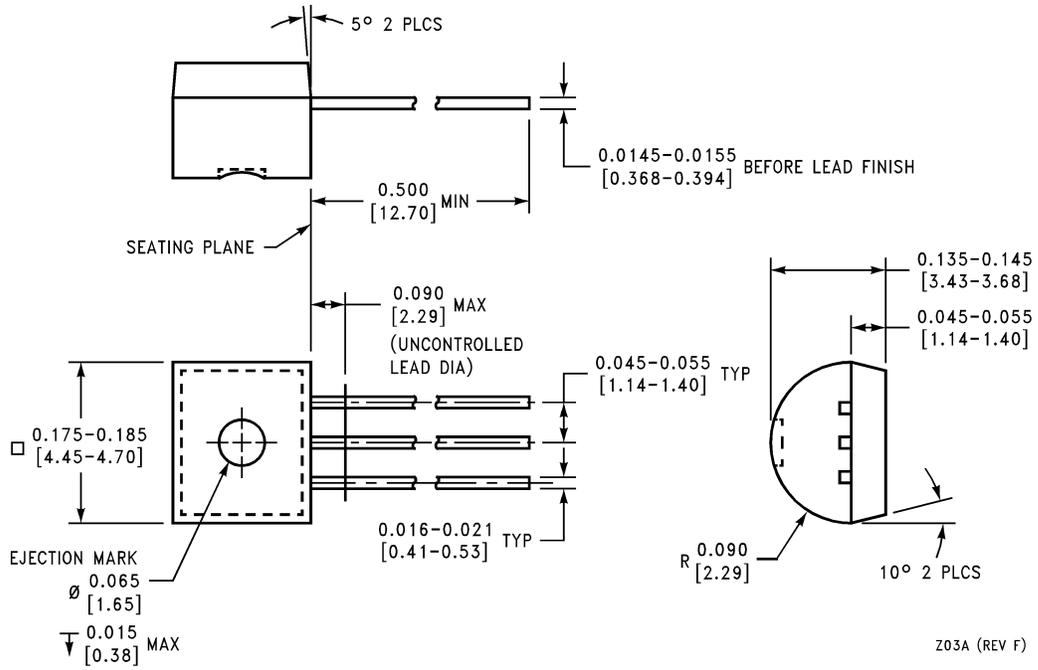
NS Package Number M08A



**SOT-23 Molded Small Outline Transistor Package (M3)
NS Package Number MF03A**

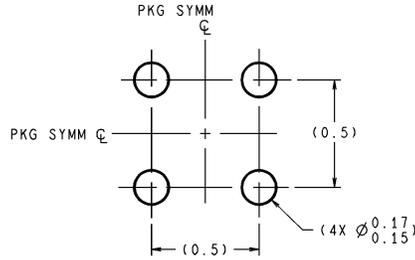
MF03A (Rev A)

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



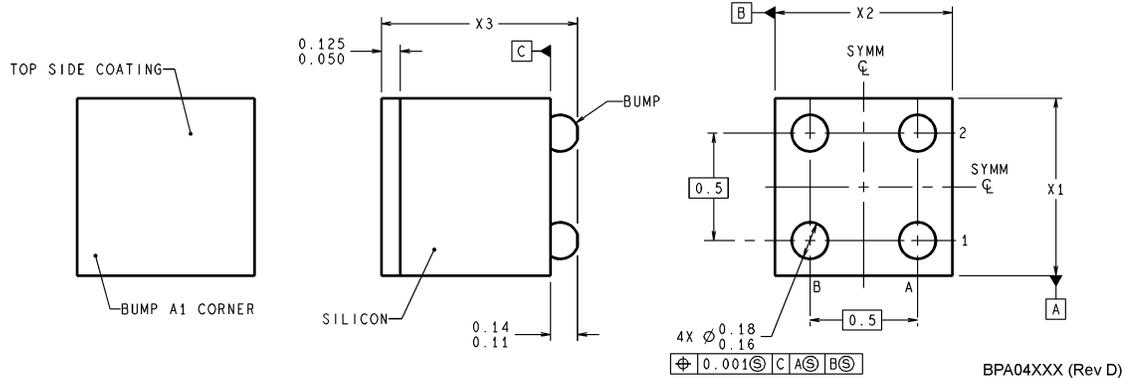
NS Package Number Z03A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



DIMENSIONS ARE IN MILLIMETERS

LAND PATTERN RECOMMENDATION



BPA04XXX (Rev D)

NOTES: UNLESS OTHERWISE SPECIFIED

1. EPOXY COATING
2. 63Sn/37Pb EUTECTIC BUMP
3. RECOMMEND NON-SOLDER MASK DEFINED LANDING PAD.
4. PIN A1 IS ESTABLISHED BY LOWER LEFT CORNER WITH RESPECT TO TEXT ORIENTATION. REMAINING PINS ARE NUMBERED.
5. XXX IN DRAWING NUMBER REPRESENTS PACKAGE SIZE VARIATION WHERE X1 IS PACKAGE WIDTH, X2 IS PACKAGE LENGTH AND X3 IS PACKAGE HEIGHT.
6. REFERENCE JEDEC REGISTRATION MO-211, VARIATION BA.

4-Bump micro SMD
X1 = 0.777 X2 = 0.904 X3 = 0.850
NS Package Number BPA04AFB

LIFE SUPPORT POLICY

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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.



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